



# MMSTA05/MMSTA06

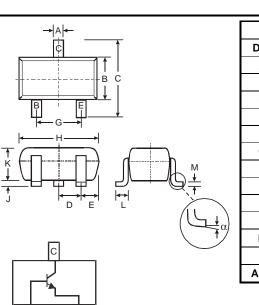
NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

#### Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (MMSTA55/MMSTA56)
- Ideal for Medium Power Amplification and Switching
- Ultra-Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Notes 3 and 4)

#### Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- MMSTA05 Marking K1H, K1G (See Page 3)
- MMSTA06 Marking K1G (See Page 3)
- Order & Date Code Information: See Page 3
- Weight: 0.006 grams (approximate)



SOT-323										
Dim	Min	Max								
Α	0.25	0.40								
В	1.15	1.35								
С	2.00 2.20									
D	0.65 N	ominal								
Е	0.30	0.40								
G	1.20	1.40								
н	1.80	2.20								
J	0.0	0.10								
κ	0.90	1.00								
L	0.25	0.40								
М	0.10	0.18								
α	0°	8°								
All Dimensions in mm										

#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

-				
Characteristic	Symbol	MMSTA05	MMSTA06	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	80	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	80	V
Emitter-Base Voltage	V <sub>EBO</sub>	4	.0	V
Collector Current - Continuous (Note 1)	Ιc	5	00	mA
Power Dissipation (Note 1)	Pd	2	00	mW
Thermal Resistance, Junction to Ambient (Note 1)	R <sub>θ</sub> JA	6	25	°C/W
Operating and Storage Temperature Range	Tj, T <sub>STG</sub>	-55 to	٥C	

#### **Electrical Characteristics** $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic		Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					1	-
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	60 80	_	V	$I_{\rm C} = 100 \mu {\rm A}, \ I_{\rm E} = 0$	
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	60 80	_	V	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$	
Emitter-Base Breakdown Voltage		V <sub>(BR)EBO</sub>	4.0	_	V	$I_{\rm E} = 100 \mu A, I_{\rm C} = 0$
Collector Cutoff Current	I <sub>CBO</sub>	_	100	nA	$V_{CB} = 60V, I_E = 0$ $V_{CB} = 80V, I_E = 0$	
Collector Cutoff Current	MMSTA05 MMSTA06	I <sub>CES</sub>		100	nA	$V_{CE} = 60V, I_{BO} = 0V$ $V_{CE} = 80V, I_{BO} = 0V$
ON CHARACTERISTICS (Note 5)						
DC Current Gain		h <sub>FE</sub>	100	_	_	$I_{C} = 10mA, V_{CE} = 1.0V$ $I_{C} = 100mA, V_{CE} = 1.0V$
Collector-Emitter Saturation Voltage		V <sub>CE(SAT)</sub>	_	0.25	V	$I_{C} = 100 \text{mA}, I_{B} = 10 \text{mA}$
Base-Emitter Saturation Voltage		V <sub>BE(SAT)</sub>		1.2	V	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 1.0V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product		fт	100	_	MHz	V <sub>CE</sub> = 2.0V, I <sub>C</sub> = 10mA, f = 100MHz

Notes: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

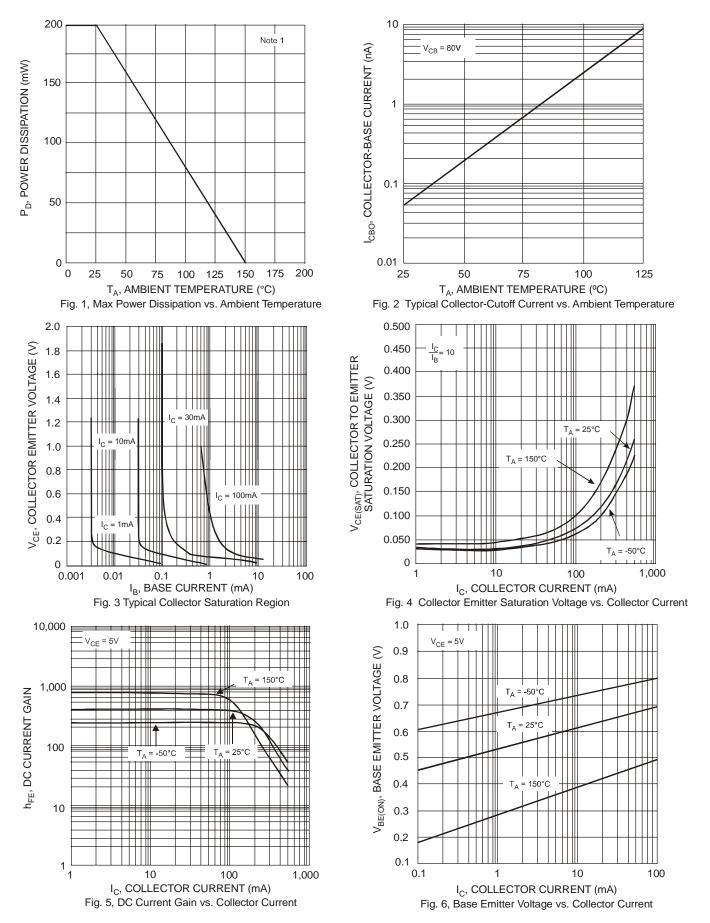
2. No purposefully added lead.

3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.

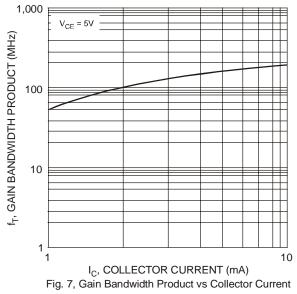
4. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

5. Short duration pulse test used to minimize self-heating effect.







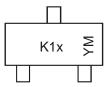


### Ordering Information (Note 4 and 6)

Device	Packaging	Shipping
MMSTA05-7-F	SOT-323	3000/Tape & Reel
MMSTA06-7-F	SOT-323	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

#### **Marking Information**



K1x = Product Type Marking Code, ex: K1H = MMSTA05 YM = Date Code Marking Y = Year ex: N = 2002 M = Month ex: 9 = September

Date Code Key															
Year	1998	1999	2000	2001	2002	2003	2004	2005	5 2006	2007	2008	2009	2010	2011	2012
Code	J	к	L	М	Ν	Р	R	s	Т	U	V	W	Х	Y	Z
Month	Jan	Fe	b	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oc	t	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		Ν	D

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